## NSN 5962-01-278-7241

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Body Length:
Between 0.930 inches and 0.970 inches
Body Width:
Between 0.245 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.175 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
6625-01-194-9786 test set, radar
Features Provided:
Low power and hermetically sealed and high impedance and 3-state output and high performance
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
17 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
35.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Ram
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 printed circuit
Shelf Life:
N/a
Unit Of Measure:
<del></del>
Demilitarization:

Fiig:

A458a0

Yes - demil/mli